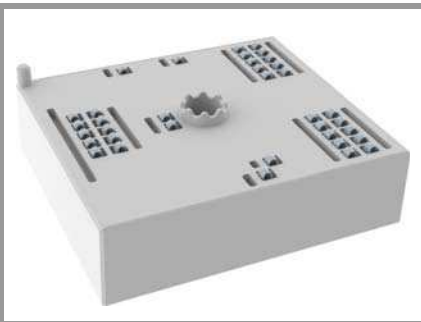


# SKiiP 24GB07E3V1



MiniSKiiP® 2 Dual

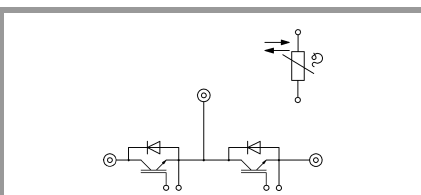
## SKiiP 24GB07E3V1

### Features

- 650V Trench IGBTs
- Robust and soft diodes in CAL technology
- Highly reliable spring contacts for electrical connections
- UL recognised: File no. E63532
- NTC T-Sensor

### Remarks

- Max. case temperature limited to  $T_C = 125^\circ\text{C}$
- Product reliability results valid for  $T_j \leq 150^\circ\text{C}$  (recommended  $T_{j,op} = -40 \dots +150^\circ\text{C}$ )



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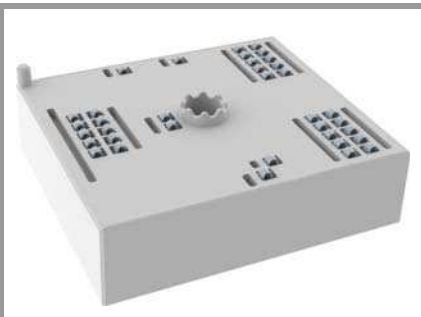
### Absolute Maximum Ratings

Symbol	Conditions	Values	Unit	
<b>Inverter - IGBT</b>				
$V_{CES}$	$T_j = 25^\circ\text{C}$	650	V	
$I_C$	$T_j = 175^\circ\text{C}$	$T_s = 25^\circ\text{C}$	185	A
		$T_s = 70^\circ\text{C}$	148	A
$I_{Cnom}$		150	A	
$I_{CRM}$	$I_{CRM} = 3 \times I_{Cnom}$	450	A	
$V_{GES}$		-20 ... 20	V	
$t_{psc}$	$V_{CC} = 360\text{ V}$ $V_{GE} \leq 15\text{ V}$ $V_{CES} \leq 650\text{ V}$	$T_j = 150^\circ\text{C}$ 6	$\mu\text{s}$	
$T_j$		-40 ... 175	$^\circ\text{C}$	
<b>Inverse - Diode</b>				
$I_F$	$T_j = 175^\circ\text{C}$	$T_s = 25^\circ\text{C}$	161	A
		$T_s = 70^\circ\text{C}$	128	A
$I_{Fnom}$		150	A	
$I_{FRM}$	$I_{FRM} = 2 \times I_{Fnom}$	300	A	
$I_{FSM}$	10 ms, sin 180°, $T_j = 150^\circ\text{C}$	828	A	
$T_j$		-40 ... 175	$^\circ\text{C}$	
<b>Module</b>				
$I_{t(RMS)}$	$T_{terminal} = 80^\circ\text{C}$ , $T_{terminal} = 80^\circ\text{C}$ , 20A per spring	200	A	
$T_{stg}$		-40 ... 125	$^\circ\text{C}$	
$V_{isol}$	AC sinus 50 Hz, t = 1 min	2500	V	

### Characteristics

Symbol	Conditions	min.	typ.	max.	Unit
<b>Inverter - IGBT</b>					
$V_{CE(sat)}$	$I_C = 150\text{ A}$ $V_{GE} = 15\text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$	1.45	1.77	V
		$T_j = 150^\circ\text{C}$	1.70	2.10	V
$V_{CE0}$	chipelevel	$T_j = 25^\circ\text{C}$	0.9	1	V
		$T_j = 150^\circ\text{C}$	0.82	0.9	V
$r_{CE}$	$V_{GE} = 15\text{ V}$ chipelevel	$T_j = 25^\circ\text{C}$	3.7	5.1	m $\Omega$
		$T_j = 150^\circ\text{C}$	5.9	8	m $\Omega$
$V_{GE(th)}$	$V_{GE} = V_{CE}$ , $I_C = 2.4\text{ mA}$	5.1	5.8	6.4	V
$I_{CES}$	$V_{GE} = 0\text{ V}$ $V_{CE} = 650\text{ V}$	$T_j = 25^\circ\text{C}$	0.1	0.3	mA
					mA
$C_{ies}$	$V_{CE} = 25\text{ V}$	f = 1 MHz	9.24		nF
$C_{oes}$	$V_{GE} = 0\text{ V}$	f = 1 MHz	0.60		nF
$C_{res}$		f = 1 MHz	0.27		nF
$Q_G$	- 8 V...+ 15 V		1360		nC
$R_{Gint}$	$T_j = 25^\circ\text{C}$		2		$\Omega$
$t_{d(on)}$	$V_{CC} = 300\text{ V}$ $I_C = 150\text{ A}$	$T_j = 150^\circ\text{C}$	107		ns
$t_r$	$R_{Gon} = 3\ \Omega$	$T_j = 150^\circ\text{C}$	42		ns
$E_{on}$	$R_{Goff} = 3\ \Omega$	$T_j = 150^\circ\text{C}$	2.2		mJ
$t_{d(off)}$	$di/dt_{on} = 4228\text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$	383		ns
$t_f$	$di/dt_{off} = 2857\text{ A}/\mu\text{s}$ $du/dt = 5140\text{ V}/\mu\text{s}$	$T_j = 150^\circ\text{C}$	47		ns
$E_{off}$	$V_{GE} = +15/-8\text{ V}$ $L_s = 25\text{ nH}$	$T_j = 150^\circ\text{C}$	5.1		mJ
$R_{th(j-s)}$	per IGBT, $\lambda_{paste} = 0.8\text{ W/K}^*\text{m}$		0.33		K/W

# SKiiP 24GB07E3V1



MiniSKiiP® 2 Dual

## SKiiP 24GB07E3V1

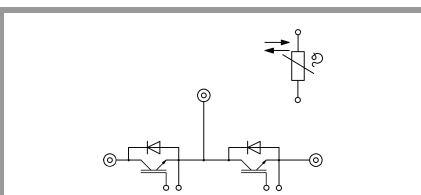
### Features

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### Remarks

- Max. case temperature limited to  $T_C = 125^\circ\text{C}$
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 $T_{j,op} = -40 \dots +150^\circ\text{C}$

Characteristics						
Symbol	Conditions		min.	typ.	max.	Unit
<b>Inverse - Diode</b>						
$V_F = V_{EC}$	$I_F = 150\text{ A}$ $V_{GE} = 0\text{ V}$ chipllevel	$T_j = 25^\circ\text{C}$		1.5	2	V
		$T_j = 150^\circ\text{C}$		1.6	2.1	V
$V_{F0}$	chipllevel	$T_j = 25^\circ\text{C}$		1	1.2	V
		$T_j = 150^\circ\text{C}$		0.9	1	V
$r_F$	chipllevel	$T_j = 25^\circ\text{C}$		3.3	4.9	m $\Omega$
		$T_j = 150^\circ\text{C}$		5	7.3	m $\Omega$
$I_{RRM}$	$I_F = 150\text{ A}$	$T_j = 150^\circ\text{C}$		175		A
$Q_{rr}$	$di/dt_{off} = 4058\text{ A}/\mu\text{s}$	$T_j = 150^\circ\text{C}$		14.9		$\mu\text{C}$
$E_{rr}$	$V_{GE} = -8\text{ V}$ $V_{CC} = 300\text{ V}$	$T_j = 150^\circ\text{C}$		3.7		mJ
$R_{th(j-s)}$	per Diode, $\lambda_{paste} = 0.8\text{ W}/\text{K}^*\text{m}$			0.45		K/W
<b>Module</b>						
$L_{CE}$				20		nH
$M_s$	to heat sink		2		2.5	Nm
w				50		g
<b>Temperature Sensor</b>						
$R_{100}$	$T_c = 100^\circ\text{C}$ ( $R_{25} = 5\text{ k}\Omega$ )			$493 \pm 5\%$		$\Omega$
$B_{25/85}$	$R_{(T)} = R_{25} \cdot \exp[B_{25/85} \cdot (1/T - 1/298)]$ , [T]=K			3420		K



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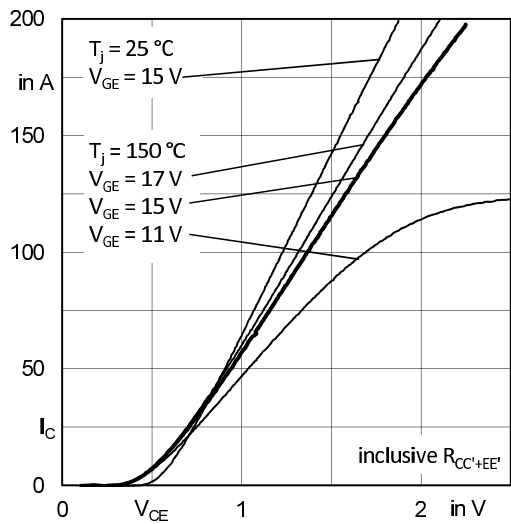


Fig. 1: Typ. output characteristic, inclusive  $R_{CC+EE}$

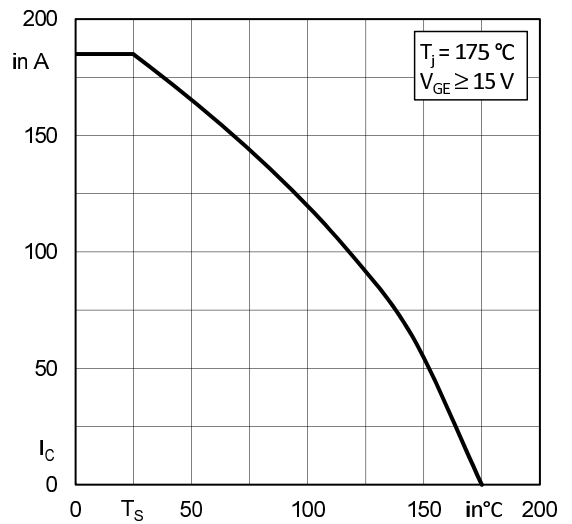


Fig. 2: Rated current vs. temperature  $I_C = f(T_S)$

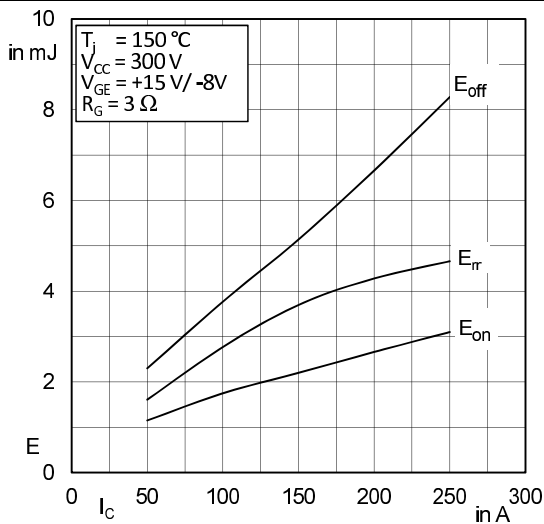


Fig. 3: Typ. turn-on /-off energy =  $f(I_C)$

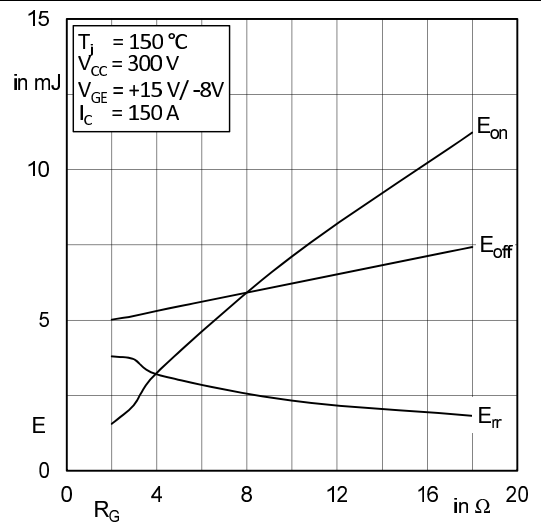


Fig. 4: Typ. turn-on /-off energy =  $f(R_G)$

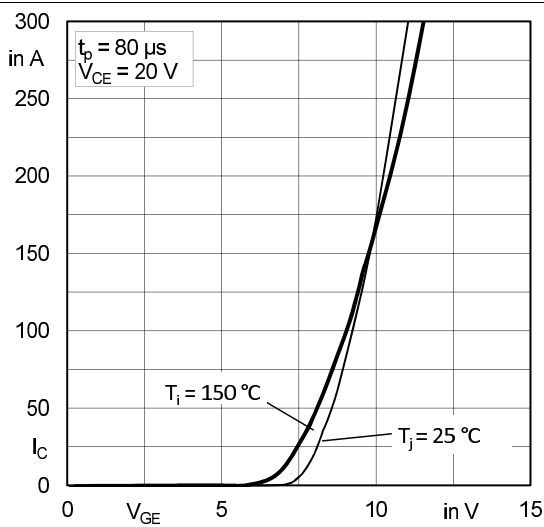


Fig. 5: Typ. transfer characteristic

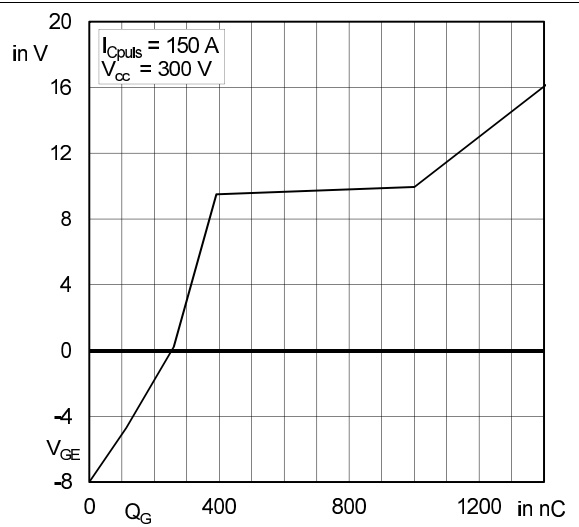
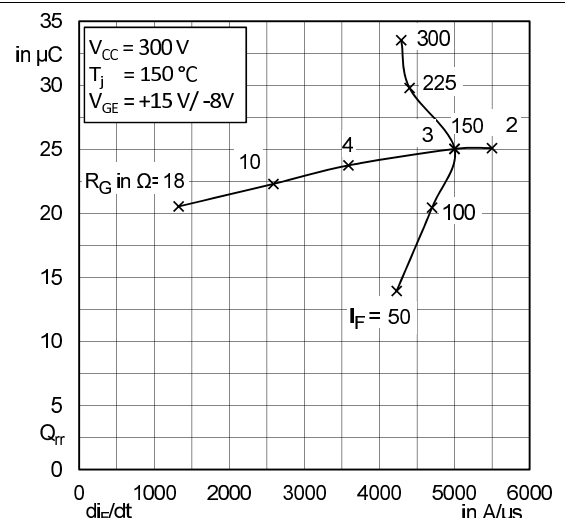
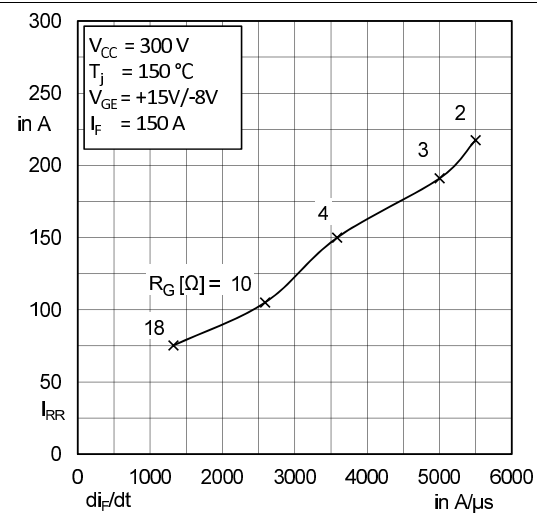
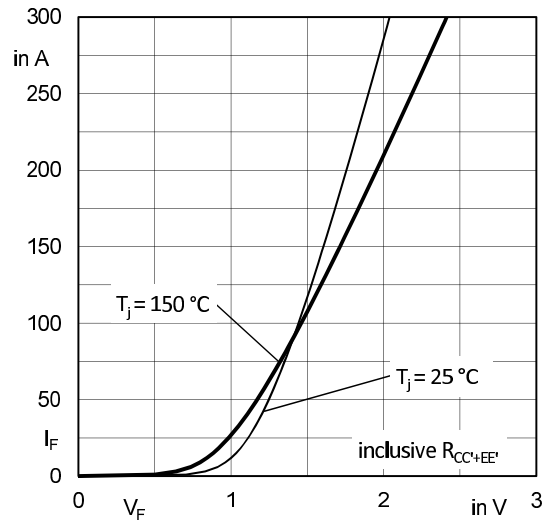
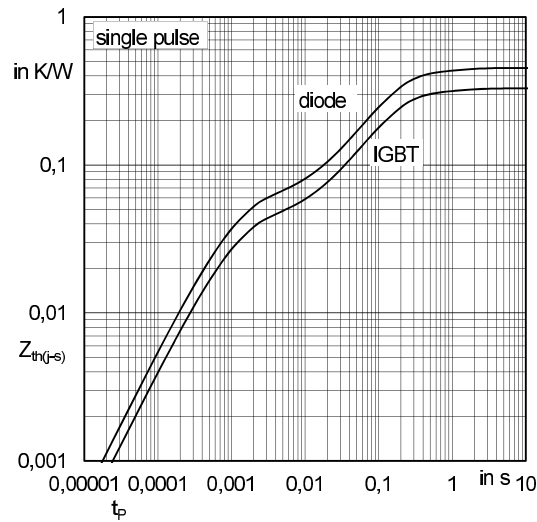
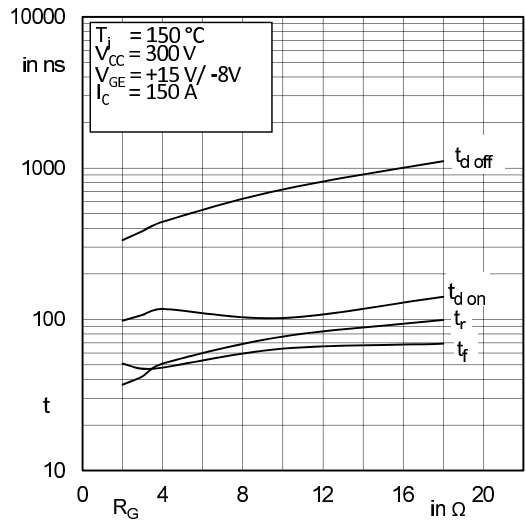
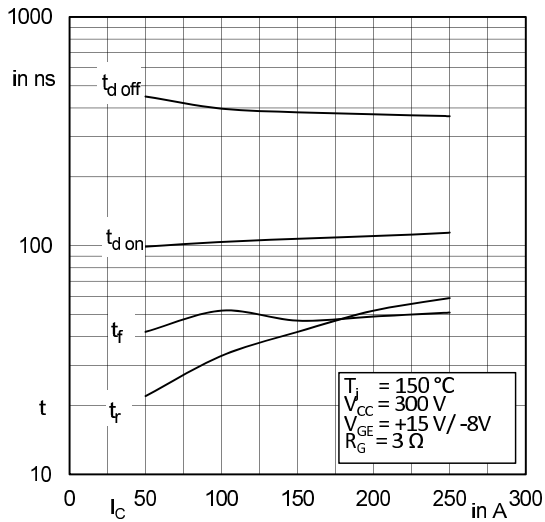
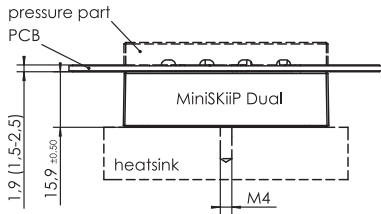


Fig. 6: Typ. gate charge characteristic



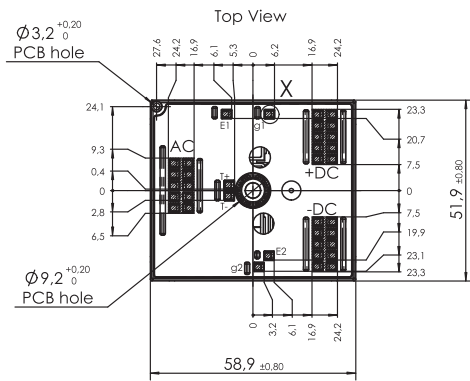
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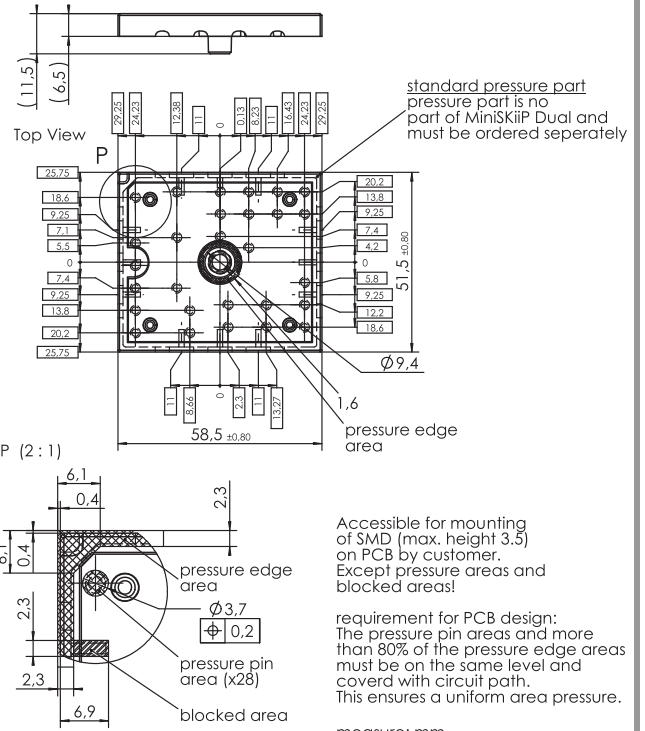
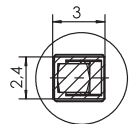
For mounting please follow the assembly instruction

requirement for PCB Design:  
The MiniSKiiP area shall be covered with a maximum of circuit paths. This ensures a uniform area pressure

measure: mm  
tolerance: +/- 0,2



X (5 : 1)  
min. PCB pad size



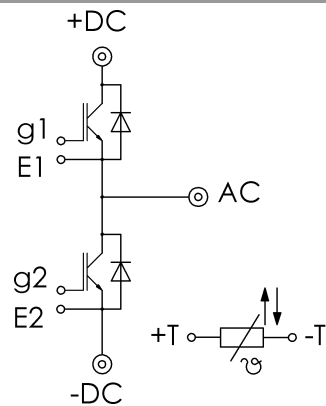
standard pressure part pressure part is no part of MiniSKiiP Dual and must be ordered separately

Accessible for mounting of SMD (max. height 3.5) on PCB by customer. Except pressure areas and blocked areas!

requirement for PCB design:  
The pressure pin areas and more than 80% of the pressure edge areas must be on the same level and covered with circuit path. This ensures a uniform area pressure.

measure: mm  
tolerance: +/- 0,2

## pinout, dimensions



⊙ power connector  
○ control connector

## pinout

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX

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